Role of Disorder in Mn G aAs, Cr G aAs, and Cr G aN

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Abstract

We present calculations of magnetic exchange interactions and critical temperature T_c in $Ga_1 \ _xMn_xAs$, $Ga_1 \ _xCr_xAs$ and $Ga_1 \ _xCr_xN$. The local spin density approximation is combined with a linear-response technique to map the magnetic energy onto a Heisenberg ham iltonion, but no signi cant further approximations are made. Special quasi-random structures in large unit cells are used to accurately model the disorder. T_c is computed using both a spin-dynamics approach and the cluster variation method developed for the classical Heisenberg model.

We show the following: (i) con gurational disorder results in large dispersions in the pairwise exchange interactions; (ii) the disorder strongly reduces T_c ; (iii) clustering in the magnetic atom s, whose tendency is predicted from total-energy considerations, further reduces T_c . Additionally the exchange interactions J(R) are found to decay exponentially with distance R³ on average; and the mean-eld approximation is found to be a very poor predictor of T_c , particularly when J(R) decays rapidly. Finally the elect of spin-orbit coupling on T_c is considered. With all these factors taken into account, T_c is reasonably predicted by the local spin-density approximation in M nG aA s without the need to invoke compensation by donor in purities.

D ilute m agnetic sem iconductors (DMS), i.e. sem iconductors doped with low concentrations of m agnetic in purities (usually Cr, Mn, or Co), have attracted much interest because of their potential application to spintronics [1, 2]. $Ga_1 \times Mn_xAs$ is the most widely studied DMS, and it continues to attract interest because it is one of the few DMS where it is generally agreed that the magnetism is carrier mediated. (This is in portant in spintronics because the magnetic state can be manipulated by electrical or optical means.)

In recent years C unie tem peratures in $Ga_1 \times Mn_xA$ s have risen steadily, reaching 170K for x 0.08 when grown in thin Mn s annealed at low tem perature [3, 4, 5]. It is generally believed defects (probably M n interstitials) m igrate out of the as-deposited Mn s during the anneal, largely eliminating donor defects that ham per ferrom agnetism. Since m ost practical applications of spintronics require room -tem perature operation, a crucial question is then, what is the ultim ate limit to T_c in the DMS com pounds, and in $Ga_1 \times Mn_xA$ s in particular?

This question was rst addressed by D ietl in his now classic paper[6], where he predicted a wide range of T_c in tetrahedrally coordinated alloys. This stimulated a great deal of interest, although there is a growing consensus that most of the claims of that paper were artifacts of the assumptions in his original model. On the other hand, A kai[7] rst used the local spin-density approximation (LSDA) to estimate T_c within the C oherent P otential Approximation (CPA) in (In M n)As; he argued that a double exchange mechanism was a more appropriate description of the magnetism than the pd exchange assumed by D ietl. Since then LSDA calculations of exchange interactions have been performed by a variety of groups [8, 9, 10, 11, 12, 13], usually extracting exchange parameters by calculating total energies of a xed atom ic but multiple-spin con gurations, or by a linear-response technique within the CPA.

To date, disorder has almost always been neglected or treated within some mean-eld (MF) approximation (MFA), either in the computation of the exchange parameters them – selves, or in the subsequent analysis of magnetization M (T) at nite-temperature, or both (though better treatments within k p theory has been reported [14]). The LSDA+MF predict a rather high T_c for $Ga_1 \times Mn_xAs$ (typically 350 400 K for x 0.08 [13]). The large discrepancy with experiment (at least in MnGaAs) is usually attributed to the very large numbers of compensating defects in real samples, which reduce T_c [3, 4, 5]. The situation remains some what uncertain because the number of defects still remaining in the best samples to date is not known.

2

This Letter addresses the issue of the ultim ate lim it to T_c in some DMS alloys (focusing on M n G aA s) by adopting relatively rigorous approach to the calculation of the magnetic exchange interactions and T_c . R andom alloys are approximated by large (128-250 atom) supercells where special quasirandom structures (SQS) [15] are used for the cation sublattice. U sing a linear-response technique within the LSDA and the linear-mu n-tin orbitals m ethod [16, 17], the magnetic energy is mapped onto a Heisenberg form [18]

$$H = \int_{ij}^{X} J(R_{ij}) \hat{e}_{i} \hat{e}$$
(1)

where the sum is over all pairs ij of magnetic atoms. To model M (T) and T_c , Eq.(1) is treated classically and integrated using a spin-dynamics (SD) technique[19]; alternatively M (T) is estimated by the cluster variation method (CVM)[20] adapted [21] to solve Eq.(1). Thus it is evaluated without recourse to empirical parameters or to the MFA.We show that the widely used MFA turns out be a very poor predictor of M (T) in these disorded, dilute alloys, dramatically overestimating T_c .

W ith SQS we can rather precisely m in ic a fully random con guration, but it is also possible to consider con gurations that deviate from random. This can be important because LSDA predicts a strong attractive interaction between m agnetic elements [8], which implies a tendency towards clustering. In brief, we show that

the disorder induces large uctuations in J_{ij} J (R_{ij}) for every connecting vector R_{ij}; The uctuations in J_{ij} reduce T_c relative to the con gurationally averaged $\overline{J}_{ij} = hJ_{ij}i$;

clustering reduces $T_{\!\rm c}$, while ordering of the magnetic elements increases $T_{\rm c}$.

Fig. 1 shows J_{ij} computed for an ensemble of 108-cation (216-atom) random supercells following the method of Ref.[17], for Ga₁ _xM n_xAs and Ga₁ _xC r_xN alloys at x= 4.6% and x=8.3% . 3 3 k-points were used, enabling the calculation of J to very distant neighbors. We chose these two alloys because they are approximately representative of limiting cases. For CrG aN, the GaN host has a wide bandgap, and the Crt₂ level falls near midgap. It broadens into an impurity band with 1/3 occupancy, and is believed to be responsible for the ferrom agnetic exchange. For MnG aAs, most of the weight of the Mnt₂-derived state falls below the valence band maximum. A second t₂ impurity band about 0.1 eV above the valence band maximum is mainly responsible for the ferrom agnetic exchange coupling

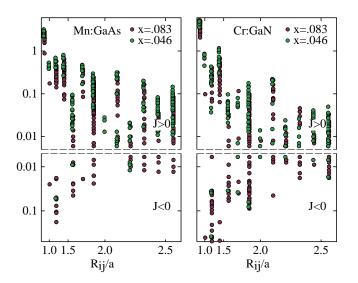


FIG. 1: Pair exchange interactions J (R_{ij}), in mRy, for MnGaAs and CrGaN at two di erent concentrations as a function of R_{ij}^3 . R_{ij} is measured in units of the lattice constant a.

in this case; the strength of J (R) depends critically on the amount of M n character in this band [22]. K atayam a-Yoshida used the x-dependence of $J_0 = {}^P_{R} \overline{J}$ (R) (computed within the CPA) to identify the ferrom agnetism obtained from LSDA with model theories [13]. Within the CPA, $J_0 = {}^{x^{1-2}}$ for CrG aN, which corresponds to a double-exchange model, while M n G aAs displays character intermediate between $J_0 = {}^{x^{1-2}}$ and the pd exchange ($J_0 = {}^{x}$) usually assumed by k p models [6, 23].

C om paring C rG aN to M n G aA s, C rG aN shows substantially stronger nearest-neighbor (NN) interactions, owing to its small lattice constant; however $\overline{J}(R_{ij})$ decays much more rapidly with R_{ij} . This is because the wave function overlap between transition metal d states decays much more rapidly for midgap states than near band-edge states. Evident also is the large dispersion in J_{ij} for xed R_{ij} (note J is drawn on a log scale): the root-mean square uctuations $J_{ij} = J_{ij}^2 J_{ij}^2$ are roughly comparable to \overline{J} . However J_{ij} increases with x, and is substantially larger for the wide-gap case (C rG aN). Note that there is little evidence in either C rG aN or M n G aA s for oscillatory RK K Y -like behavior, which in the simplest approximation predicts $J(R) = \cos(2k_F R) = R^3$. Instead, $\overline{J}(R)$ decays roughly exponentially in R^3 , corresponding to a Ferm isurface with in aginary wave number, as would obtain if the coupling were described by tunneling via a disordered in purity band [24].

We now apply Eq.(1) to compute M (T), focusing on T_c . Mean-eld theory, which estimates the eld at each site from the average eld contributed by other sites, predicts T_c well above room temperature both in M n G aA s and C r G aN [13, 25]. In spite of the rather strong di erences in the form of J (R) (F ig. 1), m ean-eld theory predicts that M n G aA s and C r G aN have roughly sim ilar T_c for x 0.08 [25]. This is because the NN interaction in the latter case is strongest, but the J decays faster with R, leading to a comparable m ean-eld [26] estim ate \overline{T}_c^{MFA} .

But it should be evident from Fig. 1 that the MFA is of questionable reliability. First, it is well known that for dilute alloys there is a percolation threshold for the onset of ferrom agnetism. (The threshold in the present case cannot be readily m apped to known m odels because J(R) is nonneglible for a rather large number of neighbors.) M oreover, the large uctuations J(R) m ay strongly a ect T_c , especially since J(R) itself is purely a function of the environm ent[8], and consequently of the local percolation path.

To obtain a precise estimate for M (T) and T_c , we adopt a spin-dynamics approach [19]. A 200 atom SQS structure (250 atom for the 4% alloy) was used to m in ic the random alloy. From the TM atoms in the SQS structure, a supercell containing 2000 M n or Cr atoms was constructed to m ake a simulation cell for prosecuting spin-dynamical simulations. Following the method described in Ref.[19], the Landau-Lifshitz (L-L) equation was integrated numerically at a xed temperature allowing the system to equilibrate, followed by a simulation for 2 10⁶ atom ic units. The L-L equations were integrated with the Bulirsch-Stoer method. A sthe L-L equation is a rst-order equation, global deam ons were used for the heat bath [19], to ensure ergodic behavior. The average magnetization \overline{M} (T) was computed as a function of temperature, and T_c was estimated from the injection point in \overline{M} (T). O wing to nite-size e ects and the stochastic character of the simulation, T_c could be determined to a precision of 5%.

Also we employed a CVM approach recently adapted to the classical Heisenberg ham iltonion [21]. This relatively simple scheme has been found to be accurate in simple 3d m agnets, overestimating T_c by 5% (similar to the usual CVM for the Ising ham iltonion [27]). We can check the validity both methods in the DMS case by comparing their predictions of T_c . Fig 2 shows T_c determined by both methods for $Ga_1 \ _xMn_xAs$ and $Ga_1 \ _xCr_xAs$: agreement between the two methods is 10%, which is quite satisfactory considering the complexity of the J_{ij} . \overline{T}_c^{MFA} is also shown: evidently the MFA rather badly overestimates T_c . $\overline{T}_c^{MFA} > T_c$ by 200K in the MnGaAs alloy, and by a somewhat larger amount in CrGaAs. The discrepancy is stillmore dramatic in CrGaN (not shown); we nd $T_c < 50$ K

5

for all concentrations studied while \overline{T}_{c}^{MFA} 600K [25]. Indeed we have found this generally to be the case when J (R) decays rapidly or when J (R)=J (R) is not sm all.

These results stand in stark contrast to the 15% discrepancy between T_c^{MFA} and T_c typically found in simplem etals. The reason is easily understood by considering the eld a mean-eld atom sees, $H_i^{eff} = P_j J_{ij} e_j$. From the exponential decay of J(R), it is evident that H_i will be dominated by the nearest neighbors. But for dilute alloys, near-neighbors are not su cent to form a percolation path. This is immediately evident in the extrem e case of a NN pair of magnetic atom swell separated from any otherm agnetic atom s: the contribution to T_c^{MFA} from this pair would be high, even though the pair would actually contribute nothing to ferrom agnetism.

In Ref. [10] a small discrepancy between T_c^{M-FA} and a more sophisticated calculation for T_c was reported. In that calculation the CPA was used to construct an average \overline{J}_{ij} and M (T) modeled by constructing a fcc lattice of magnetic atoms, using concentrated-weighted \overline{J}_{ij} for the exchange parameters. It would seem that their conclusions are an artifact of the neglect of congurational disorder (except in the computation of \overline{J}_{ij}). Better would be to estimate \overline{J}_{ij} within the CPA, and then construct a disordered simulation cell using the \overline{J}_{ij} to estimate M (T). Still this approach neglects uctuations J, which as we have seen are comparable to \overline{J}_{ij} itself. To assess the e ect of uctuations, we repeated the calculation for T_c within the CVM, replacing the environment-specie c J_{ij} with the congurationally averaged \overline{J}_{ij} . For G a_{1-x}M n_xAs at x=0.08, the e ect of disorder (\overline{J}_{ij} ! J_{ij}) was to reduce T_c by 50 K. (It is interesting that the M FA predicts the opposite trend, because of an articial tendency for M^{M-FA} (T) to track whichever site i has the largest H_i^{eff} . Then $T_c^{M-FA} = \overline{T}_c^{M-FA}$ is positive [26] and increases with J=J. This explains why a tight-binding+M F analysis [24] predicted that disorder increases T_c .)

We next consider the elects of nonrandom ness. As noted above, realDMS alloys should exhibit some clustering owing to the attractive interaction between magnetic elements[8]. The true situation is complicated by the nonequilibrium grow th required to stabilize the alloy in the zincblende structure. Nevertheless the Mn-Mn or Cr-Crbinding energy is calculated [8] to be an order of magnitude larger than the grow th temperature (250K), and some pairing or other clustering should be expected, particularly since lm smust be annealed to obtain good T_c. There is some experimental evidence for a tendency to cluster[28].

The e ect of clustering on T_c in $Ga_{0.92}Mn_{0.08}As$ was studied by a simple model. To

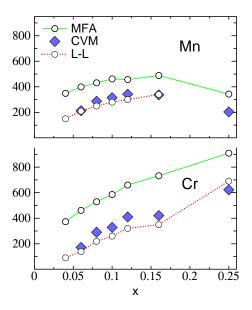


FIG. 2: Dependence of T_c (K) on x in $Ga_1 _x M n_x A s$ and $Ga_1 _x C r_x A s$. Solid lines: T_c computed from the MF \overline{T}_c^{MFA} [26]. Dotted line: T_c extracted from spin-dynamics simulations of Eq. 1. D iam onds: T_c computed from the Heisenberg C luster Variation M ethod.

characterize the con gurational disorder we adopt the standard Ising form alism, and assign 1 to each cation site (+1 for Mn and 1 for Ga). The random (SQS) con quration = was constructed by searching for con gurations which best approximate the ideal random con guration for pair correlation functions $P_{R_{ij}} = h_i_j i$ (and som e higher-order correlation functions) up to some xed distance. For a random con guration, $P_R = (2x)$ $(1)^2$ independent of R. To param eterize the clustering in a simple manner, we adopted the NN pair correlation function P1 as a measure of clustering. Starting from an initial SQS con guration, a simulated annealing cycle was performed by generating a set of site con gurations with increasing P_1 , corresponding to longer annealing times (For simplicity, P_n (n > 1) was optimized to be (2x ~ 1) 2 for each con guration.) $J_{\rm ij}$ and $T_{\rm c}$ were computed by the CVM and MFA [26] as a function of P₁; see Fig. 3. T_c is rather strongly reduced with increasing P1. This is perhaps not surprising since increased clustering in plies m ore distant average separation between atom s, which is deleterious to links in the percolation path. Even within the MFA T_c changes slightly, albeit for a di erent reason. In that case, there is an increase in NN pairs, which would increase T_c, but at the same time there is some increase in the likelihood of three- and higher body neighbors. The presence of a third neighbor has the e ect of reducing the pairw ise J_{ij} [8], and is the origin of the factor-of-three variations in

the NN J in Fig. 1.

W e also considered the ordered lim it, by putting 1 M n in a 24-atom unit cell, corresponding to x=0.083. In this case P_1 decreases to 2/3, and T_c increases to 350K (see Fig. 3). Thus we conclude that ordering increases T_c , while clustering decreases T_c . Perhaps not suprisingly, the MFA T_c approaches the CVM result in the ordered case, since percolation is less critical.

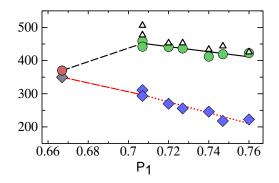


FIG. 3: Dependence of T_c (K) on the pair correlation function P_1 in $Ga_{0.92}Mn_{0.08}As$. The random (SQS) con guration corresponds to $P_1 = 0.7056$. (Two SQS structures were calculated.) D iam onds show T_c computed with CVM; circles show \overline{T}_c^{MFA} , and triangles show T_c^{MFA} . The point at $P_1 = 2=3$ corresponds to the ordered compound.

To conclude, we have shown that ferrom agnetism is very sensitive to con gurational disorder in DMS alloys, and that with proper treatment of disorder T_c is reasonably predicted by the LSDA for G a_{1 x}M n_xAs, without needing to invoke compensating defects. We brie y consider two important sources of error from elementsm issing in the theory. First, spin-orbit coupling strongly reduces T_c in k pm odels. We estimated its elect by computing the change in \overline{T}_c^{MFA} when the L S coupling is added to the LSDA ham iltonion. For G_{\$\vert{\mathcal{e}}2\mathbf{M}} n_{0.08}As, \overline{T}_c^{MFA} was reduced by 10%. Finally, the LSDA itself will overestimate T_c somewhat [22]. In a future work we will present a reliable parameter-free theory that corrects the principal errors in LSDA | most importantly the M n d character at E_F | and quantify the extent to which the LSDA overestimates T_c. Finally, we conclude that the present calculations represent a rather strict upper bound to T_c, and that for random or clustered G a_{1 x}M n_xAs alloys, T_c > 250 K is unlikely.}

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degrees of freedom which leads to a more complicated form for the partition function: $Z_{ij} = {P \choose 1}(2l+1)i_l({ij = T \choose i})i_l(J_{ij}=T)i_l({ij = T \choose j})$, where $i_l(z) = {P \choose (-2z)}I_{l+1=2}(z)$ and $I_n(z)$ is the modiled Bessel function of the rst kind. Cluster methods can include strong correlation among atom s, which the MFA neglects. The CVM accurately describes interactions within the clusters (pair clusters in our case). The interactions of the cluster with the environment is described by renormalizing elds ^{ij}.

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